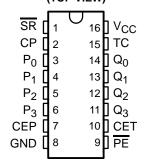
- **Function, Pinout, and Drive Compatible** With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of **Equivalent FCT Functions**
- **Edge-Rate Control Circuitry for Significantly Improved Noise** Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and **Output Logic Levels**
- CY54FCT163T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT163T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

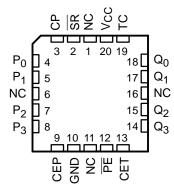
description

high-speed The 'FCT163T devices are synchronous modulo-16 binary counters. They are synchronously presettable for application in programmable dividers. These devices have two

CY74FCT163CT...Q OR SO PACKAGE (TOP VIEW)



CY54FCT163T . . . L PACKAGE (TOP VIEW)



NC - No internal connection

types of count-enable (CEP and CET) inputs, plus a terminal-count (TC) output for versatility in forming synchronous multistaged counters. The 'FCT163T devices have a synchronous-reset ($\overline{\sf SR}$) input that overrides counting and parallel loading, and allows the outputs to be reset simultaneously on the rising edge of the clock.

These devices are fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

PIN DESCRIPTION

NAME	DESCRIPTION
CEP	Count-enable parallel input
CET	Count-enable trickle input
CP	Clock pulse input (active rising edge)
SR	Synchronous-reset input (active low)
Р	Parallel data inputs
PE	Parallel-enable input (active low)
Q	Flip-flop outputs
TC	Terminal-count output



testing of all parameters.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

TA	PACI	KAGE [†]	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - Q	Tape and reel	5.8	CY74FCT163CTQCT	FT163-3
-40°C to 85°C	SOIC - SO	Tube	5.8	CY74FCT163CTSOC	FCT163C
		Tape and reel	5.8	CY74FCT163CTSOCT	FC1163C
–55°C to 125°C	LCC – L	Tube	11.5	CY54FCT163TLMB	·

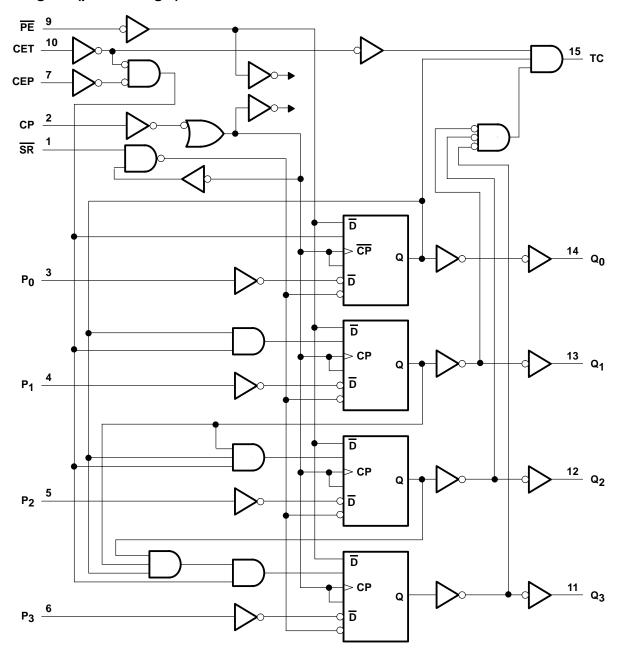
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

	INP	UTS		ACTION ON THE RISING
SR	PE	CET	CEP	CLOCK EDGE(S)
L	Χ	Х	Χ	Reset (clear)
Н	L	Χ	Χ	$\text{Load }(P_n \to Q_n)$
Н	Н	Н	Н	Count (incremental)
Н	Н	L	Χ	No change (hold)
Н	Н	Χ	L	No change (hold)

H = High logic level, L = Low logic level, X = Don't care

logic diagram (positive logic)



SCCS015A - MAY 1994 - REVISED OCTOBER 2001

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5	\mbox{V} to 7 \mbox{V}
DC input voltage range	0.5	\mbox{V} to 7 \mbox{V}
DC output voltage range	–0.5	\mbox{V} to 7 \mbox{V}
DC output current (maximum sink current/pin)		120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package		90°C/W
SO package		57°C/W
Ambient temperature range with power applied, T _A	. −65°C t	to 135°C
Storage temperature range, T _{sta}	. −65°C t	to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

		CY54FCT163T			CY	4FCT16	3T	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			8.0			0.8	V
loh	High-level output current			-12			-32	mA
lOL	Low-level output current			32			64	mA
TA	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	CY	′54FCT16	3T	CY	74FCT16	3T	UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
Vii	$V_{CC} = 4.5 \text{ V}, \qquad I_{IN} = -18 \text{ mA}$		-0.7	-1.2				V
VIK	$V_{CC} = 4.75 \text{ V}, \qquad I_{IN} = -18 \text{ mA}$					-0.7	-1.2	V
	$V_{CC} = 4.5 \text{ V}, \qquad I_{OH} = -12 \text{ mA}$	2.4	3.3					
Voн	$V_{CC} = 4.75 \text{ V}$ $I_{OH} = -32 \text{ mA}$				2			V
	$I_{OH} = -15 \text{ mA}$		-		2.4	3.3		
VOL	$V_{CC} = 4.5 \text{ V}, \qquad I_{OL} = 32 \text{ mA}$		0.3	0.55				V
VOL.	$V_{CC} = 4.75 \text{ V}, I_{OL} = 64 \text{ mA}$					0.3	0.55	V
V_{hys}	All inputs		0.2			0.2		V
١,	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = V_{CC}$,	5				μА
ΙΙ	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = V_{CC}$						5	μΑ
Iн	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$			±1				μА
чн	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$						±1	μΑ
IIL	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$			±1				μА
'IL	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$						±1	μΑ
lost	V _{CC} = 5.5 V, V _{OUT} = 0 V	-60	-120	-225				mA
los‡	V _{CC} = 5.25 V, V _{OUT} = 0 V				-60	-120	-225	IIIA
l _{off}	V _{CC} = 0 V, V _{OUT} = 4.5 V			±1			±1	μΑ
loo	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} \le 0.2 \text{ V}, \qquad V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2				mA
Icc	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} \le 0.2 \text{ V}, \qquad V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.1	0.2	IIIA
Alee	$V_{CC} = 5.5 \text{ V}, V_{IN} = 3.4 \text{ V}$, $f_1 = 0$, Outputs open		0.2	2				mA
∆lCC	$V_{CC} = 5.25 \text{ V}, V_{IN} = 3.4 \text{ V}$, $f_1 = 0$, Outputs open					0.2	2	ША
ICCD¶	$V_{CC} = 5.5 \text{ V, Load mode, Outputs open,}$ One bit switching at 50% duty cycle, $CEP = CET = \overline{PE} = GND, \overline{SR} = V_{CC},$ $V_{IN} \le 0.2 \text{ V or } V_{IN} \ge V_{CC} - 0.2 \text{ V}$							mA/
"CCD"	$\begin{split} &V_{CC}=5.25 \text{ V, Load mode, Outputs open,} \\ &\text{One bit switching at } 50\% \text{ duty cycle,} \\ &\text{CEP}=\text{CET}=\overrightarrow{PE}=\text{GND, } \overrightarrow{SR}=\text{V}_{CC}, \\ &\text{V}_{IN}\leq 0.2 \text{ V or } \text{V}_{IN}\geq \text{V}_{CC}-0.2 \text{ V} \end{split}$					0.06	0.12	MHz

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



^{*} Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, Ios tests should be performed last.

 $[\]$ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

[¶] This parameter is derived for use in total power-supply calculations.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		TEST COMPLETION	10	CY	54FCT16	3T	CY	74FCT16	3T	LINUT
PARAMETER		TEST CONDITION	V S	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT
	V _{CC} = 5.5 V, Load mode,	One bit switching at f ₁ = 5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	$f_0 = 10 \text{ MHz},$	50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4				
	Outputs open, <u>CEP</u> = CET = PE = GND,	Four bits switching at f ₁ = 5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2				
IC#	$\overline{SR} = V_{CC}$	50% duty cycle	V _{IN} = 3.4 V or GND		2.9	8.2				mA
ıC	$V_{CC} = 5.25 \text{ V},$ $f_0 = 10 \text{ MHz},$	One bit switching at f ₁ = 5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	IIIA
	Load mode,	50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$					1.2	3.4	
	Outputs open, CEP = CET = PE = GND,	Four bits switching at f ₁ = 5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					1.6	3.2	
	SR = V _{CC}	50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$					2.9	8.2	
C _i					5	10		5	10	pF
Co					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 $^{\#}$ IC = ICC + Δ ICC \times DH \times NT + ICCD (f₀/2 + f₁ \times N₁)

Where:

IC = Total supply current

I_{CC} = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I_{CC} formula.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			CY54FC	T163T	CY74FC1	163CT	LINUT	
			MIN	MAX	MIN	MAX	UNIT	
4	Dulas duration high ar law	Clock (load)	5		4			
t _W	Pulse duration, high or low	Clock (count)	8		5		ns	
		P before CP↑	5.5		3.5			
t _{su}	Setup time, high or low	PE or SR before CP↑	13.5		7.6		ns	
		CEP or CET before CP↑	13		7.6			
		P after CP↑	2		1.5			
t _h	Hold time, high or low	PE or SR after CP↑	1.5		1		ns	
		CEP or CET after CP↑	0		0			



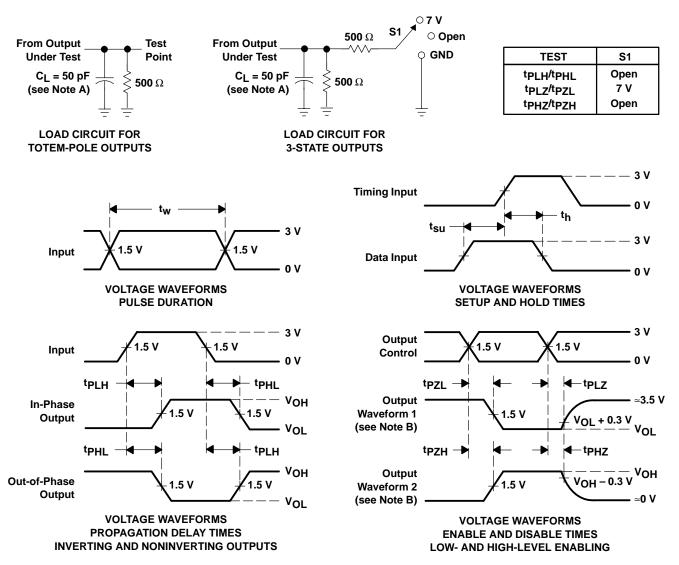
CY54FCT163T, CY74FCT163T 4-BIT BINARY COUNTERS

SCCS015A - MAY 1994 - REVISED OCTOBER 2001

switching characteristics over operating free-air temperature range (see Figure 1)

	PARAMETER	FROM	то	CY54FC	T163T	CY74FC1	T163CT	UNIT
	PARAIVIETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
tPLH	Propagation delay	СР	Q	2	11.5	1.5	5.8	no
tPHL	(PE high)	CF	y	2	11.5	1.5	5.8	ns
^t PLH	Propagation delay	СР	TC	2	10	1.5	5.2	ns
tPHL	(PE low)	GF .	10	2	10	1.5	5.2	115
tPLH		СР	TC	2	16.5	1.5	7.8	ns
tPHL		GF .	10	2	16.5	1.5	7.8	110
^t PLH		CET	TC	1.5	9	1.5	4.4	nc
tPHL		CET	10	1.5	9	1.5	4.4	ns

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms







com 21-May-2007

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CY54FCT163TLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
CY74FCT163CTQCT	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT163CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT163CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT163CTSOC	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT163CTSOCE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT163CTSOCG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT163CTSOCT	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT163CTSOCTE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT163CTSOCTG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

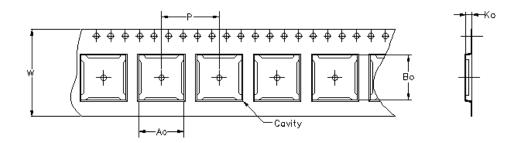
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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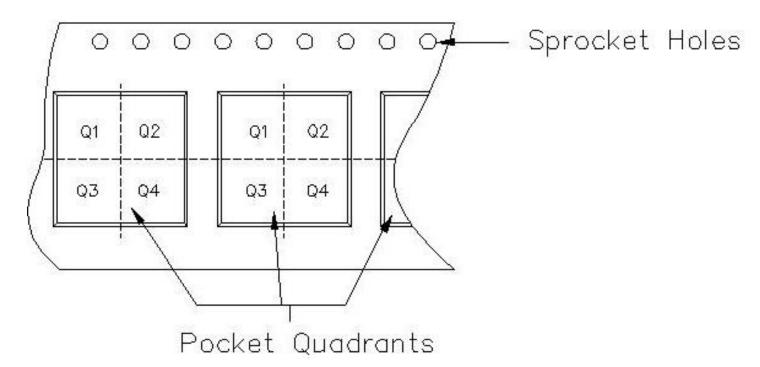
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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.				
Bo =	Dimension	designed	to	accommodate	the	component	length.				
Ko =	Dimension	designed	to	accommodate	the	component	thickness.				
W =	W = Overall width of the carrier tape.										
P = 1	Pitch betwe	en succes	ssiv	e cavity center	ვ,						

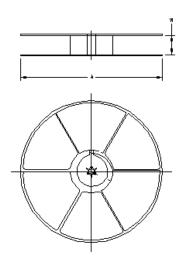


TAPE AND REEL INFORMATION



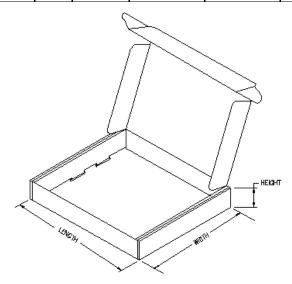
26-Apr-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT163CTQCT	DBQ	16	FMX	330	0	6.4	5.2	2.1	8	12	Q1
CY74FCT163CTSOCT	DW	16	TAI	330	16	10.75	10.7	2.7	12	16	Q1



TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CY74FCT163CTQCT	DBQ	16	FMX	338.1	340.5	20.64
CY74FCT163CTSOCT	DW	16	TAI	346.0	346.0	33.0



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Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
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